

by a substrate, wherein the interlayer insulator is located at least partially between the reflective pixel electrode and the substrate, and

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a film comprising molybdenum nitride formed immediately below and in contact with the reflective pixel electrode, and above and contacting the interlayer insulator, so that the molybdenum nitride is at least partially located between and contacting each of the reflective pixel electrode and the interlayer insulator so that a bottom surface of the molybdenum nitride is located over and contacting a top surface of the interlayer insulator and a top surface of the molybdenum nitride is located under and contacting the reflective pixel electrode.

7. (Amended) A liquid crystal display comprising:

a pair of substrates,

a liquid crystal layer between the pair of substrates,

C2
a laminated layer provided on at least one of the substrates, wherein the laminated layer comprises an insulating film and a film comprising molybdenum nitride laminated to and over at least part of the insulating film, so that the molybdenum nitride contacts an upper surface of the insulating film; and

a reflective metal film having a light reflecting function and provided in at least one pixel region of the display for contributing to displaying of images in the display, wherein the reflective metal film is formed on the laminated layer so as to contact the molybdenum nitride.

11. (Amended) A liquid crystal display (LCD) comprising:

at least one thin film transistor (TFT),

an insulating layer at least partially provided over the TFT, and wherein address lines of the LCD are in communication with the TFT;

at least one reflective pixel electrode defining at least part of a pixel of the LCD;

and

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a film comprising molybdenum in direct contact with the under-side of said reflective pixel electrode, so that the molybdenum is in directly contact with the under-side of the reflective pixel electrode and an upper surface of the insulating layer between which the molybdenum is directly sandwiched.

12. (Amended) An electronic device comprising:

a substrate supporting an insulating layer and a conductive electrode layer; and

a layer comprising molybdenum nitride, wherein the molybdenum nitride is located between and contacting each of the insulating layer and the conductive electrode layer, such that the molybdenum nitride is located below the conductive electrode layer and above the insulating layer so that the insulating layer is between the substrate and the molybdenum nitride, so that a bottom surface of the molybdenum nitride is located over and contacting a top surface of the insulating layer and a top surface of the molybdenum nitride is located under and contacting the conductive electrode.

Please add the following new claims: